

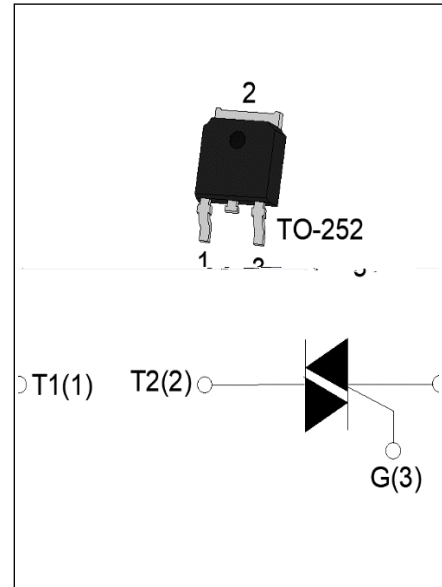


## JST12E-600C 12A TRIAC

Rev.A.1.0

The JST12E-600C triac is suitable for general purpose AC switching. It can be used as an ON/OFF function in applications such as heating regulation, induction motor starting circuits, for phase control operation in light dimmers, motor speed controllers. Package TO-263 is RoHS compliant.

Symbol	Value	Unit
$I_{T(RMS)}$	12	A
$V_{DRM}/V_{RRM}$	600	V
$I_{GT} / / /$	25/25/25/50	mA



Parameter	Symbol	Value	Unit
Storage junction temperature range	$T_{stg}$	-40-150	
Operating junction temperature range	$T_j$	-40-125	
Repetitive peak off-state voltage ( $T_j=25^\circ\text{C}$ )	$V_{DRM}$	600	V
Repetitive peak reverse voltage ( $T_j=25^\circ\text{C}$ )	$V_{RRM}$	600	V
RMS on-state current ( $T_c = 103^\circ\text{C}$ )	$I_{T(RMS)}$	12	A
Non repetitive surge peak on-state current (full cycle, $t_p=20\text{ms}$ , $T_j=25^\circ\text{C}$ )	$I_{TSM}$	120	A
Non repetitive surge peak on-state current (full cycle, $t_p=16.6\text{ms}$ , $T_j=25^\circ\text{C}$ )		132	
$I^2t$ value for fusing ( $t_p=10\text{ms}$ , $T_j=25^\circ\text{C}$ )	$I^2t$	72	$\text{A}^2\text{s}$
Critical rate of rise of on-state current ( $I_G=2k I_{GT}$ , $f=100\text{Hz}$ , $T_j=125^\circ\text{C}$ )	-	80	$\text{A}/\mu\text{s}$
	-	40	
Peak gate current ( $t_p=20\mu\text{s}$ , $T_j=125^\circ\text{C}$ )	$I_{GM}$	4	A
Average gate power dissipation ( $T_j=125^\circ\text{C}$ )	$P_{G(AV)}$	0.5	W
Peak gate power	$P_{GM}$	10	W
Peak pulse voltage ( $T_j=25^\circ\text{C}$ ; non-repetitive, off-state; FIG.8)	$V_{pp}$	1	kV

( $T_j=25$  unless otherwise specified)

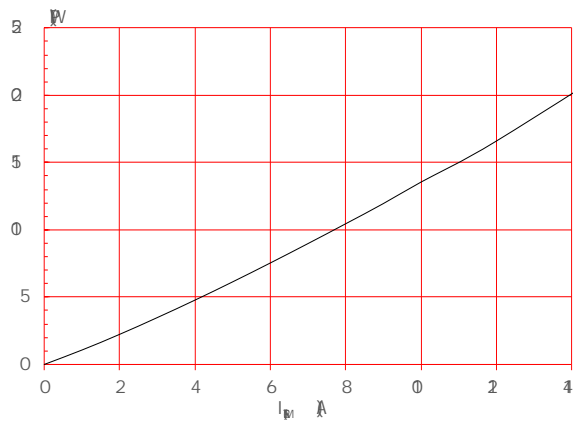
Symbol	Test Condition	Quadrant	Value		Unit
$I_{GT}$	$V_D=12V R_L=33$	- -	MAX.	25	mA
				50	
$V_{GT}$		ALL	MAX.	1	V
$V_{GD}$	$V_D=V_{DRM} T_j=125$ $R_L=3.3K$	ALL	MIN.	0.2	V
$I_L$	$I_G=1.2I_{GT}$	- -	MAX.	40	mA
				90	
$I_H$	$I_T=500mA$		MAX.	30	mA
$dV/dt$	$V_D=400V$ Gate Open $T_j=125$		MIN.	800	$V/\mu s$
$(dV/dt)_c$	$(dI/dt)_c=5.3A/ms, T_j=125$		MIN.	6	$V/\mu s$
$t_{on}$	$I_G=80mA I_A=400mA I_R=40mA$ $T_j=25$		TYP.	5	$\mu s$
$t_{off}$				50	

Symbol	Parameter		Value(MAX.)	Unit
$V_{TM}$	$I_{TM}=17A t_p=380\mu s$	$T_j=25$	1.5	V
$V_{TO}$	Threshold voltage	$T_j=125$	0.77	V
$R_D$	Dynamic resistance	$T_j=125$	35	m
$I_{DRM}$	$V_D=V_{DRM} V_R=V_{RRM}$	$T_j=25$	5	$\mu A$
$I_{RRM}$		$T_j=125$	0.4	mA

Symbol	Parameter	Value	Unit
$R_{th(j-c)}$	junction to case (AC)	1.3	$/W$
$R_{th(j-a)}$	junction to ambient (AC, in free air, $S=2cm^2$ )	45	$/W$



**FIG.1** Maximum power dissipation versus RMS on-state current



**FIG.2:** RMS on-state current versus case temperature

**FIG.7:** Relative variations of gate trigger current, holding current and latching current versus junction temperature

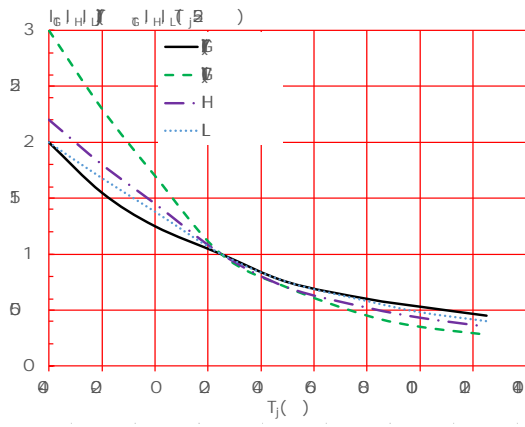
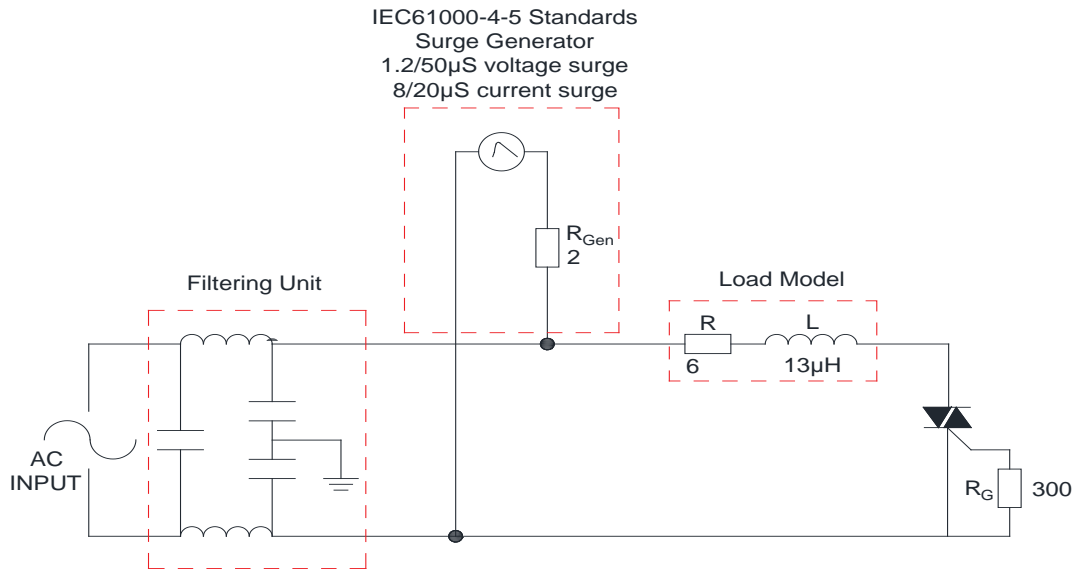


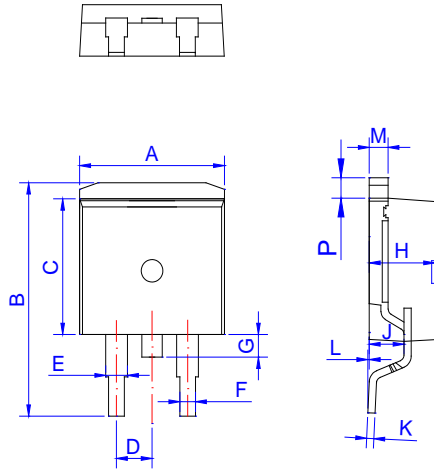
FIG.8 Test circuit for inductive and resistive loads to IEC-61000-4-5 standards



Order code	Voltage $V_{DRM}/V_{RRM}$ (V)	IGT(mA)		Package	Base qty. (pcs)	Delivery mode
		-	-			
JST12E-600C	600	25	50	TO-263	50	Tube
JST12E-600C-TR					800	Tape & Reel

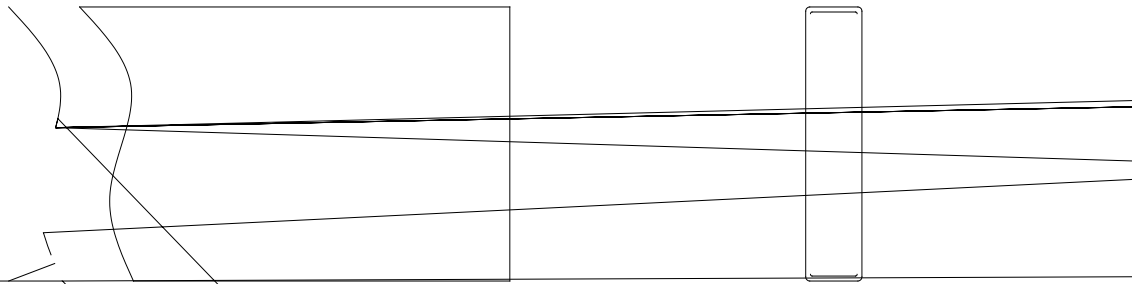
**Document Revision History**

Date	Revision	Changes
Apr.14, 2023	A.1.0	Last updated



Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	9.90		10.20	0.390		0.402
B	14.70		15.80	0.579		0.622
C	9.40		9.60	0.37		0.378
D	2.40		2.70	0.094		0.106
E	1.20		1.50	0.047		0.059
F	0.75		0.85	0.029		0.033
G	1.00		1.50	0.039		0.059
H	4.40		4.70	0.173		0.185
J	2.30		2.70	0.091		0.106
K	0.38		0.55	0.015		0.022
L	0	0.10	0.25	0	0.004	0.010
M	1.25		1.35	0.049		0.053
P	1.20		1.50	0.047		0.059






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